NSN 5961-01-276-1187

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-276-1187 **Inclosure Material:** Plastic **Overall Length:** Between 0.285 inches and 0.375 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.188 inches and 0.210 inches **Function For Which Designed:** Transient suppressor Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-201 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 58.9 breakdown voltage, dc and 65.1 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes drain current nanoamperes and 200.00 amperes forward current, average preset **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: